



2N7002ZW

Power MOSFET

300mA, 60V N-CHANNEL ENHANCEMENT MODE MOSFET

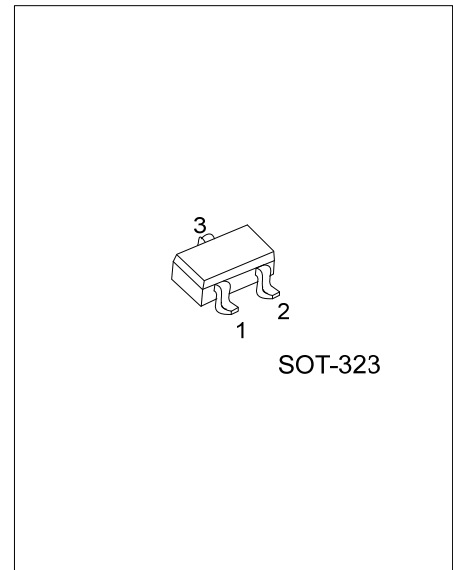
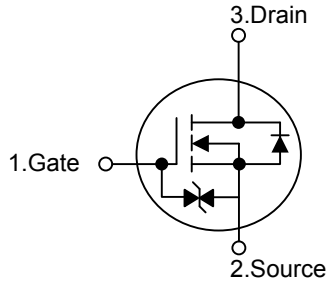
DESCRIPTION

The UTC **2N7002ZW** uses advanced technology to provide excellent $R_{DS(ON)}$, low gate charge and low gate voltages during operation. This device is suitable for use as a load switch or in PWM applications.

FEATURES

- * Low Reverse Transfer Capacitance
- * ESD Protected
- * Fast Switching Capability
- * Avalanche Energy Specified
- * Improved dv/dt Capability, High Ruggedness

SYMBOL



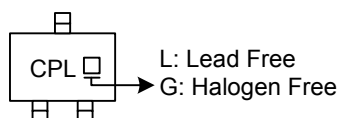
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2N7002ZWL-AL3-R	2N7002ZWG-AL3-R	SOT-323	G	S	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>2N7002ZWG-AL3-R</p> <ul style="list-style-type: none"> (1) Packing Type (2) Package Type (3) Green Package 	<ul style="list-style-type: none"> (1) R: Tape Reel (2) AL3: SOT-323 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise specified.)

PARAMETER	SYMBOL	RATINGS	UNIT
Drain-Source Voltage	V_{DSS}	60	V
Gate-Source Voltage	V_{GSS}	± 20	V
Drain Current	Continuous	300	mA
	Pulse(Note 2)	800	
Power Dissipation	P_D	200	mW
Derating above $T_A=25^\circ\text{C}$		1.6	mW/ $^\circ\text{C}$
Junction Temperature	T_J	+150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

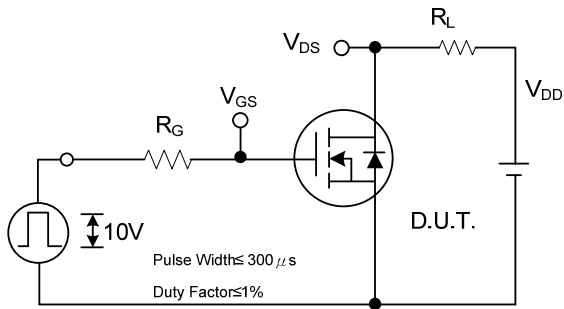
■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=10\mu A$	60			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$			1.0	μA
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 10	μA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0		2.5	V
Static Drain-Source On-Resistance (Note)	$R_{DS(ON)}$	$V_{GS}=10V, I_D=300mA$			4.0	Ω
		$V_{GS}=4.5V, I_D=50mA$			6.0	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C_{ISS}	$V_{DS}=25V, V_{GS}=0V, f=1.0MHz$		22	50	pF
Output Capacitance	C_{OSS}		9	25	pF	
Reverse Transfer Capacitance	C_{RSS}		4	5.0	pF	
SWITCHING PARAMETERS						
Turn-ON Delay Time	$t_{D(ON)}$	$I_D=0.2A, V_{DD}=30V, V_{GS}=10V,$		1.3	20	ns
Turn-OFF Delay Time	$t_{D(OFF)}$	$R_L=150\Omega, R_G=10\Omega$		4.2	30	ns
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
Maximum Continuous Drain-Source Diode Forward Current	I_S				300	mA
Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}				0.8	A
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=200mA$ (Note)		0.88	1.3	V

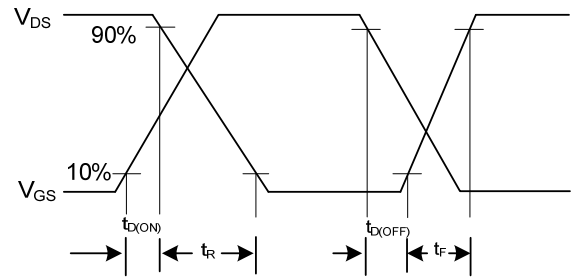
Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.

2. Pulse width $\leq 300\mu s$, Duty cycle $\leq 1\%$

■ TEST CIRCUITS AND WAVEFORMS

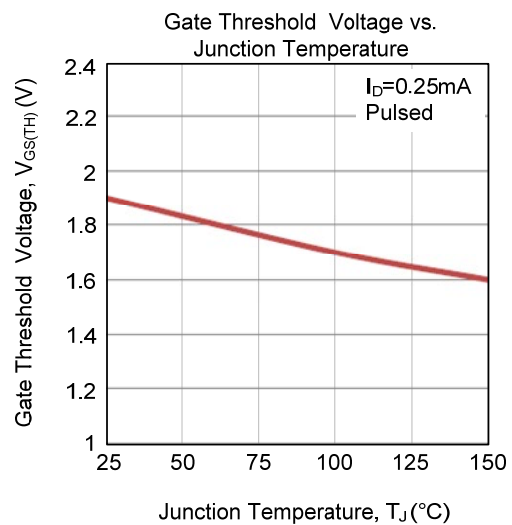
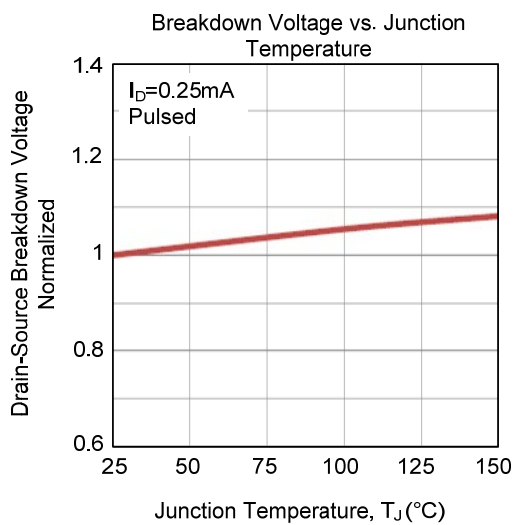
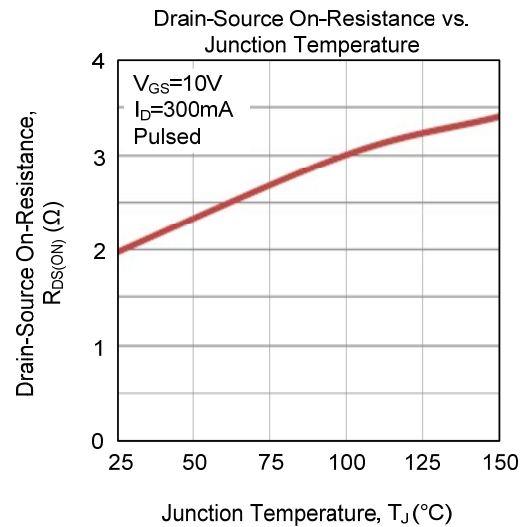
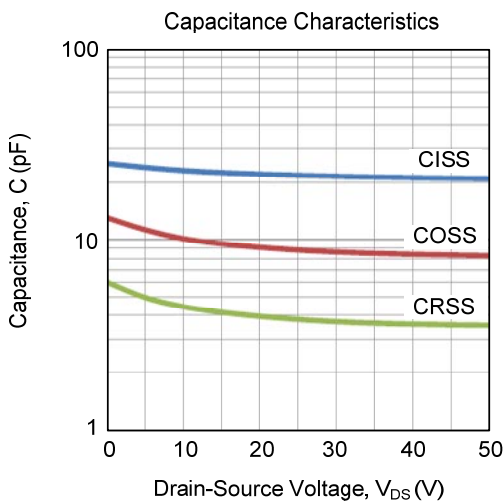
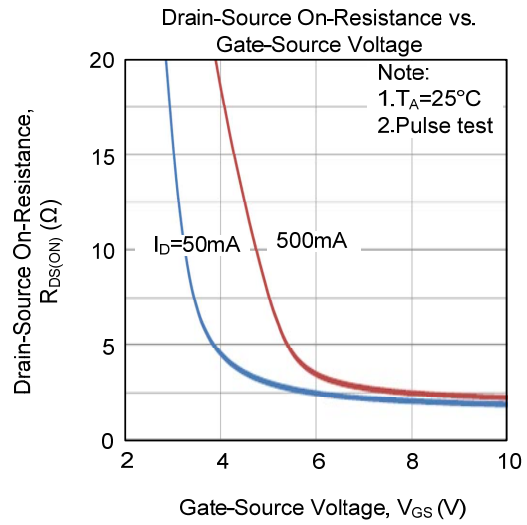
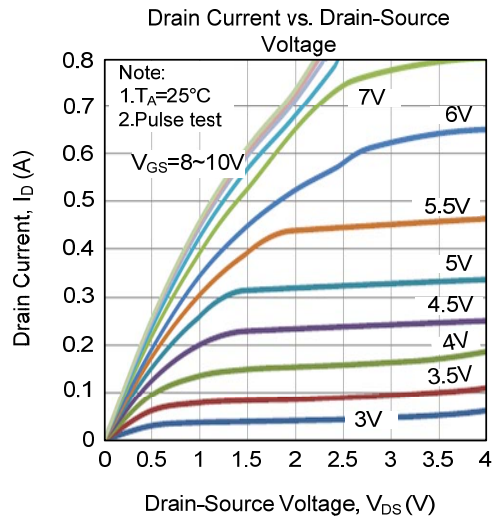


Switching Test Circuit

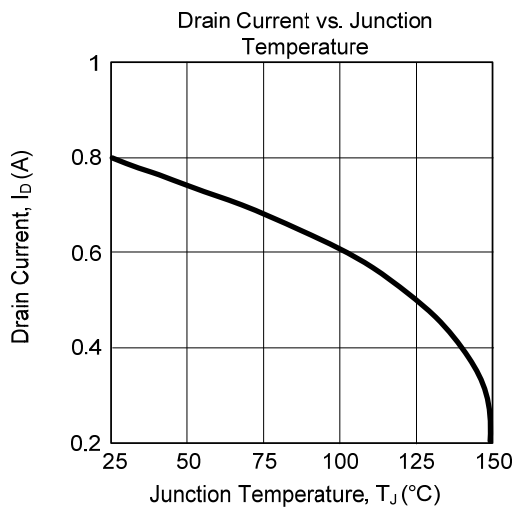
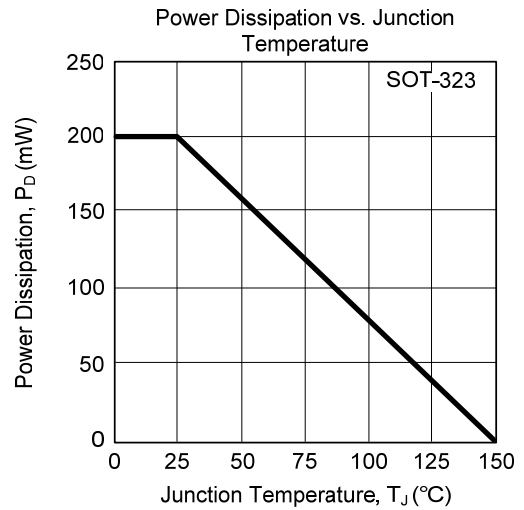
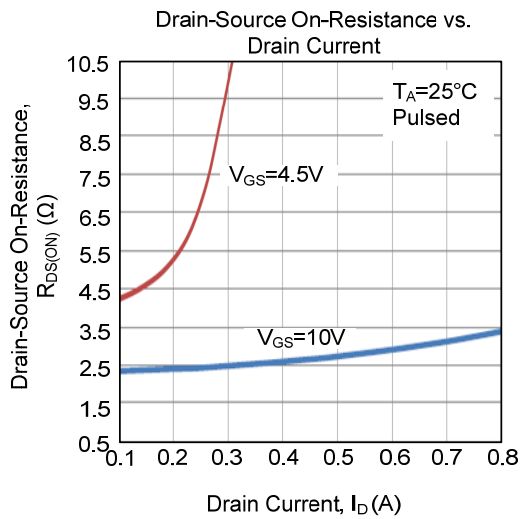
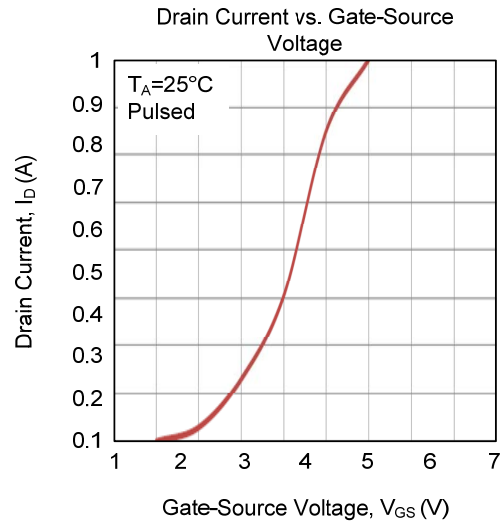
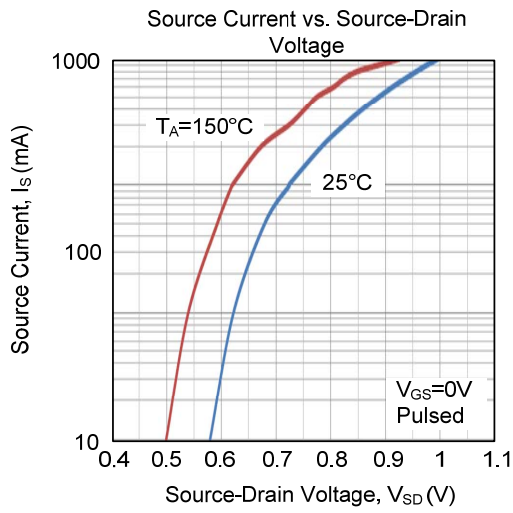


Switching Waveforms

TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



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